

Low-Voltage Dual SPDT Analog Switch

UM3257 DFN12 3.0×1.6

General Description

The UM3257 is dual SPDT analog switch fabricated with silicon gate CMOS technology. It achieves very low propagation delay and $R_{DS(ON)}$ resistances while maintaining CMOS low power dissipation. These make it ideal for portable and battery power applications.

The switch conducts signals within power rails equally well in both directions when on, and blocks up to the power supply level when off. Break-before-make is guaranteed.

The select pin has over-voltage protection that allows voltages above V_{CC} , up to 6.5V to be present on the pin without damage or disruption of operation of the part, regardless of the operating voltage.

The UM3257 can maintain low power consumption for rail-to-rail signaling as long as the control signal input is held at a level that is greater than V_{IH} minimum and less than V_{IL} maximum by improving the control circuitry input buffer. so the part can be used in mixed voltage rail environments, especially services the mobile handset applications very well allowing for the direct interface with baseband processor general purpose I/Os, and it is no longer necessary to have the control input equal to V_{CC} to maintain low power consumption

The UM3257 is in a 12-pin, ROHS compliant, DFN12 package. It measures 3.0×1.6mm. The leads are spaced at a pitch of 0.5mm and are finished with lead free Ni-Pd. The small package makes it ideal for use in portable electronics such as cell phones, digital cameras and PDAs.

Applications

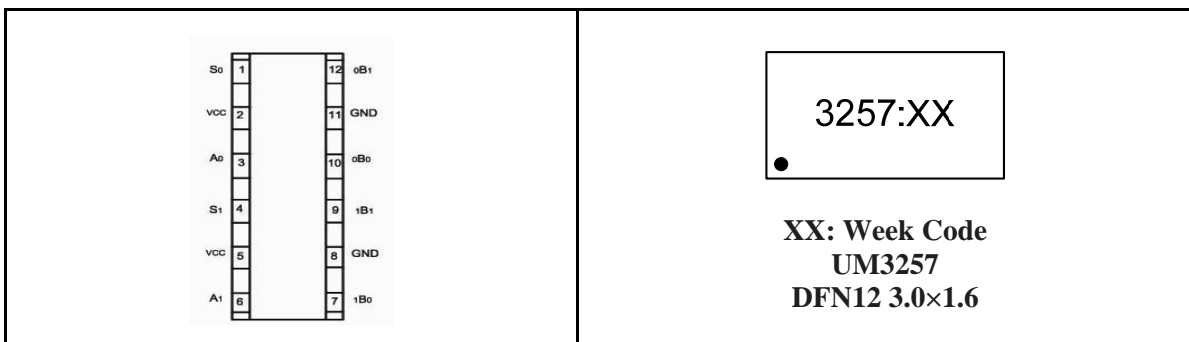
- Sample-and-Hold Circuits
- Battery-Powered Equipment
- Audio and Video Signal Routing
- Communication Circuits

Features

- Lower I_{CC} when the S Input is within the Required V_{IH} and V_{IL} Bounds
- Low ON-State Resistance (10Ω)
- Control Inputs are 5V Tolerant
- Low Charge Injection
- Excellent ON-State Resistance Matching
- Low Total Harmonic Distortion (THD)
- 1.65V to 5.5V Single-Supply Operation
- ESD Performance:
Human Body Model > 2kV
Machine Model > 200V
- DFN12 Package
- Pb-Free Package

Pin Configurations

Top View



Ordering Information

Part Number	Packaging Type	Marking Code	Shipping Qty
UM3257	DFN12 3.0×1.6	3257	3000pcs/7 Inch Tape & Reel

Function Table

Select Input	Function
L	B0 Connected to A
H	B1 Connected to A

Absolute Maximum Ratings

Symbol	Parameter	Limit	Unit
V_{CC}	Supply Voltage	-0.5 to +6.5	V
V_{IS}	DC Switch Input Voltage (Note 1)	-0.5 to ($V_{CC}+0.5$)	
V_{IN}	DC IN Voltage (Note 1)	-0.5 to +6.5	
I_{IK}	DC Input Diode Current @ $V_{IN}<0V$	-50	mA
I_{OUT}	DC Output Current	128	
I_{CC}/I_{GND}	DC V_{CC} or Ground Current	+100	
T_J	Junction Temperature Under Bias	+150	°C
T_{STG}	Storage Temperature	-65 to +150	
T_L	Junction Lead Temperature (Soldering, 10 Seconds)	260	
θ_{JA}	Thermal Resistance	350	°C/W
P_D	Power Dissipation @ +85°C	180	mW

Note 1: The input and output negative voltage ratings may be exceeded if the input and output diode current ratings are observed.

Recommended Ratings (Note2)

Symbol	Parameter	Limit	Unit
V_{CC}	Supply Voltage Operating	1.65 to 5.5	V
V_{IS}	Switch Input Voltage	0 to V_{CC}	
V_{IN}	Select Input Voltage	0 to V_{CC}	
V_{OUT}	Output Voltage	0 to V_{CC}	
T_A	Operating Temperature	-55 to +125	°C
t_r, t_f	Input Rise and Fall Time Control Input $V_{CC}=2.3V$ to 3.6V Control Input $V_{CC}=4.5V$ to 5.5V	0 to 10 0 to 5.0	ns/V

Note 2: Select input must be held HIGH or LOW, it must not float.

Electrical Characteristics

Symbol	Parameter	Test Conditions	V _{CC} (V)	Temp	Limits (-40°C to 85°C)			Unit
					Min	Typ	Max	
DC Electrical Characteristics								
	Analog Signal Range		V _{CC}	Full	0		V _{CC}	V
I _{IN}	Input Leakage Current	0 ≤ V _{IN} ≤ 5.5V	0 to 5.5	Room Full		±0.05	±0.1 ±1	μA
I _{OFF}	OFF State Leakage Current	0 ≤ A, B ≤ V _{CC}	1.65 to 5.5	Room Full		±0.05	±0.1 ±1	μA
V _{IH}	Input High Voltage		1.65 to 1.95 2.3 to 5.5	Full	0.75V _{CC} 0.7V _{CC}			V
V _{IL}	Input Low Voltage		1.65 to 1.95 2.3 to 5.5	Full			0.25V _{CC} 0.3V _{CC}	V
I _{CC}	Quiescent Supply Current	V _{IN} =V _{CC} or GND I _O =0	5.5	Room Full			1.0 10	μA
R _{ON}	On-Resistance (Note3)	V _{IN} =0V, I _O =30mA V _{IN} =2.4V, I _O =-30mA V _{IN} =4.5V, I _O =-30mA	4.5	Full		3.0 5.0 7.0	6.0 8.0 13	Ω
		V _{IN} =0V, I _O =24mA V _{IN} =3V, I _O =-24mA	3.0	Full		4.0 10	8.0 19	
		V _{IN} =0V, I _O =8mA V _{IN} =2.3V, I _O =-8mA	2.3	Full		5.0 13	9.0 24	
		V _{IN} =0V, I _O =4mA V _{IN} =1.65V, I _O =-4mA	1.65	Full		6.5 17	12 39	
R _{RANGE}	On Resistance Over Signal Range (Note3, 7)	I _A =-30mA, 0 ≤ V _{Bn} ≤ V _{CC}	4.5	Full			25	Ω
		I _A =-24mA, 0 ≤ V _{Bn} ≤ V _{CC}	3.0	Full			50	
		I _A =-8mA, 0 ≤ V _{Bn} ≤ V _{CC}	2.3	Full			100	
		I _A =-4mA, 0 ≤ V _{Bn} ≤ V _{CC}	1.65	Full			300	
ΔR _{ON}	On Resistance Match Between Channels (Note3, 4, 5)	I _A =-30mA, V _{Bn} = 3.15V	4.5	Room		0.15		Ω
		I _A =-24mA, V _{Bn} = 2.1V	3.0	Room		0.2		
		I _A =-8mA, V _{Bn} = 1.6V	2.3	Room		0.5		
		I _A =-4mA, V _{Bn} = 1.15V	1.65	Room		0.5		
R _{FLAT}	On Resistance Flatness (Note3, 4, 6)	I _A =-30mA, 0 ≤ V _{Bn} ≤ V _{CC}	5.0	Room		5.0		Ω
		I _A =-24mA, 0 ≤ V _{Bn} ≤ V _{CC}	3.3	Room		10		
		I _A =-8mA, 0 ≤ V _{Bn} ≤ V _{CC}	2.5	Room		24		
		I _A =-4mA, 0 ≤ V _{Bn} ≤ V _{CC}	1.8	Room		110		

Note 3: Measured by the voltage drop between A and B pins at the indicated current through the switch. On Resistance is determined by the lower of the voltages on the two (A or B Ports).

Note 4: Parameter is characterized but not tested in production.

Note 5: $\Delta R_{ON} = |R_{ON(A00Bn)} - R_{ON(A11Bn)}|$ measured at identical V_{CC}, temperature and voltage levels.

Note 6: Flatness is defined as the difference between the maximum and minimum value of On Resistance over the specified range of conditions.

Note 7: Guaranteed by design.

Electrical Characteristics (Continued)

Symbol	Parameter	Test Conditions	V _{CC} (V)	Temp	Limits (-40°C to 85°C)			Unit
					Min	Typ	Max	
AC Electrical Characteristics								
t _{PHL} t _{PLH}	Propagation Delay Bus to Bus (Note 9)	V _I =OPEN	1.65 to 1.95 2.3 to 2.7 3.0 to 3.6 4.5 to 5.5	Room		1.2 0.8 0.3		ns
t _{PZL} t _{PZH}	Output Enable Time Turn On Time (A to Bn)	V _I =2×V _{CC} for t _{PZL} V _I =0V for t _{PZH}	1.65 to 1.95 2.3 to 2.7 3.0 to 3.6 4.5 to 5.5	Full	7.0 3.5 2.5 1.7		32 14 7.6 5.7	ns
t _{PLZ} t _{PHZ}	Output Disable Time Turn Off Time (A Port to B Port)	V _I =2×V _{CC} for t _{PLZ} V _I =0V for t _{PHZ}	1.65 to 1.95 2.3 to 2.7 3.0 to 3.6 4.5 to 5.5	Full	3.0 2.0 1.5 0.8		28 15 11 8	ns
t _{BBM}	Break Before Make Time (Note 8)	R _L =50Ω, C _L =35pF	1.65 to 1.95 2.3 to 2.7 3.0 to 3.6 4.5 to 5.5	Full	0.5 0.5 0.5 0.5			ns
Q _{INJ}	Charge Injection (Note 8)	C _L =0.1nF, V _{GEN} =0V, R _{GEN} =0Ω	5.0 3.3	Room		7.0 3.0		pC
O _{IRR}	Off Isolation (Note 10)	R _L =50Ω, f=10 MHz	1.65 to 5.5	Room		-55		dB
Xtalk	Crosstalk	R _L =50Ω, f=10 MHz	1.65 to 5.5	Room		-54		dB
BW	-3dB Bandwidth	R _L =50Ω	2.5 to 5.5	Room		250		MHz
THD	Total Harmonic Distortion (Note8)	R _L =600Ω, 0.5V _{P-P} , f=600Hz to 20kHz	2.5 5.0	Room		0.014 0.004		%
Capacitance								
C _{IN}	IN Pin Input Capacitance (Note11)	V _{CC} =0V				2.3		pF
C _{IO-B}	B Port Off Capacitance (Note11)	V _{CC} =5.0V				6.5		pF
C _{IOA-ON}	A Port Capacitance when Switch is Enabled (Note11)	V _{CC} =5.0V				18.5		pF

Note 8: Guaranteed by design.

Note 9: This parameter is guaranteed by design but not tested. The bus switch contributes no propagation delay other than the RC delay of the On Resistance of the switch and the 35 pF load capacitance, when driven by an ideal voltage source (zero output impedance).

Note 10: Off Isolation=20log₁₀ [V_A/V_{Bn}].

Note 11: T_A=+25°C, f=1MHz, Capacitance is characterized but not tested in production.

Test Circuits/Timing Diagrams

NOTE: Input driven by 50 Ω source terminated in 50 Ω
 NOTE: C_L includes load and stray capacitance
 NOTE: Input PRR = 1.0 MHz; t_{WJ} = 500 ns

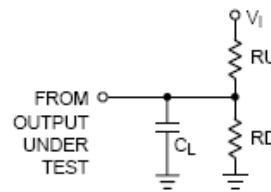


Figure 1 . AC Test Circuit

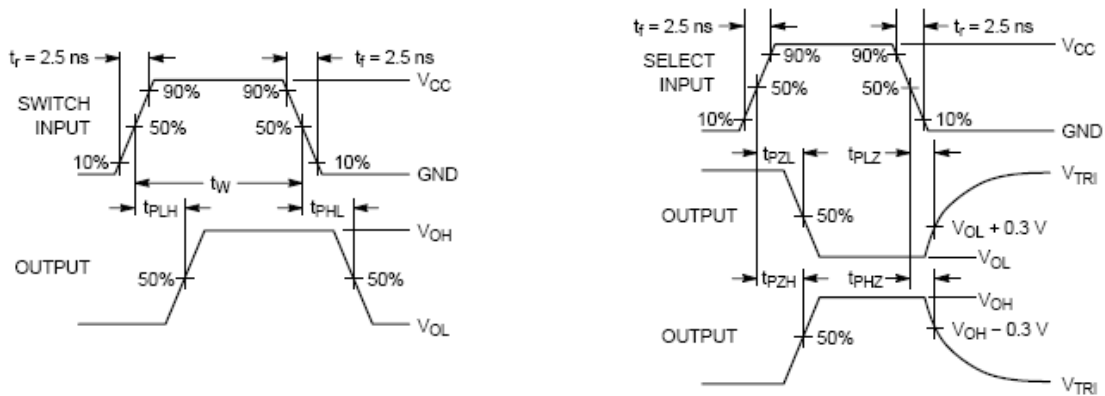


Figure 2 . AC Waveforms



Figure 3 . Break Before Make Interval Timing

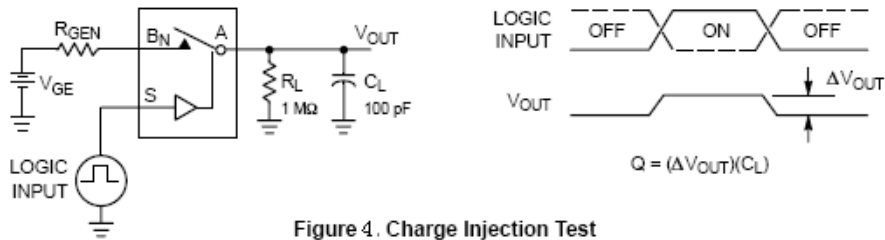


Figure 4. Charge Injection Test

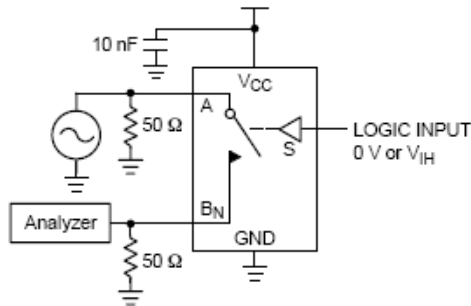


Figure 5. Off Isolation

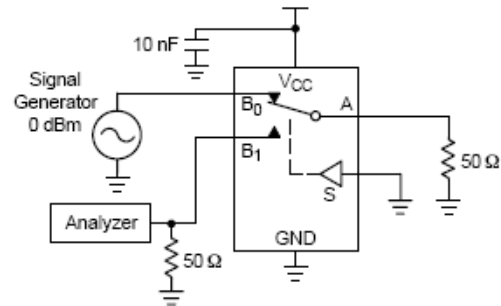


Figure 6. Crosstalk

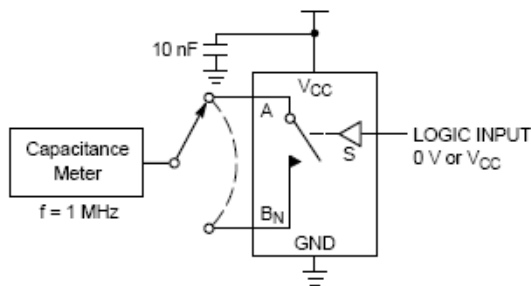


Figure 7. Channel Off Capacitance

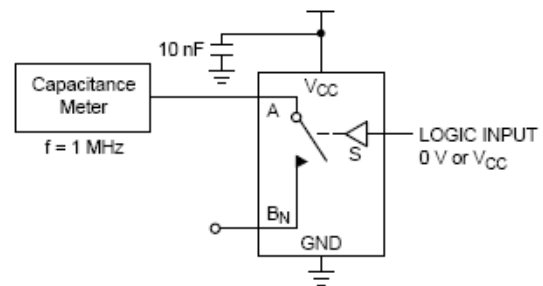


Figure 8. Channel On Capacitance

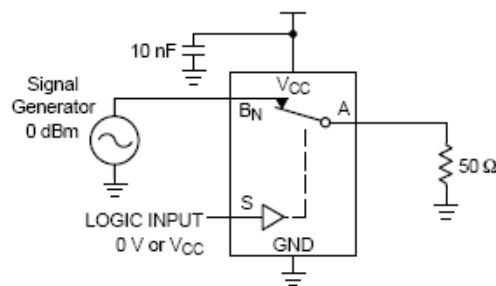
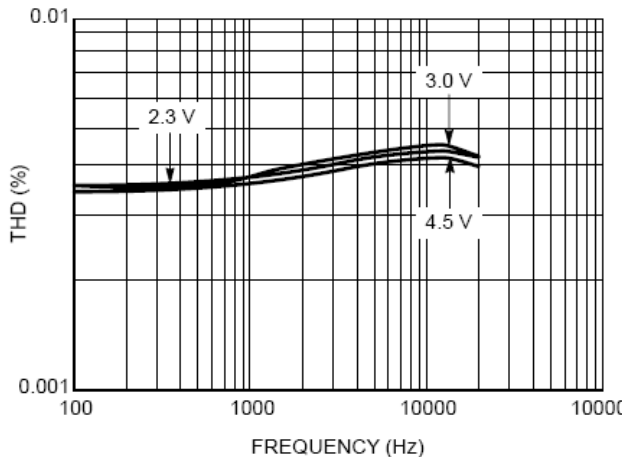


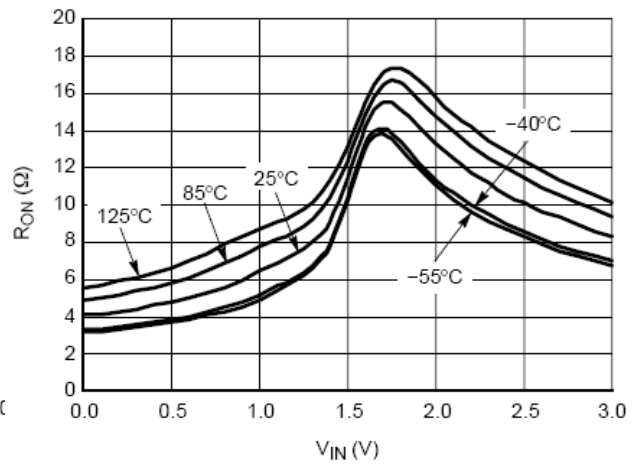
Figure 9. Bandwidth

Typical Operating Characteristics

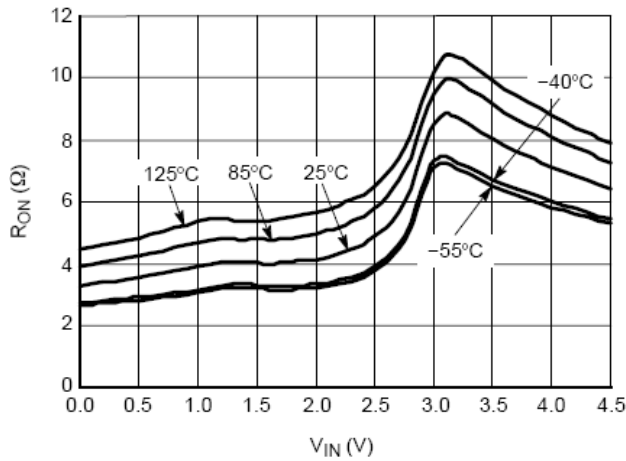
Total Harmonic Distortion vs. Frequency



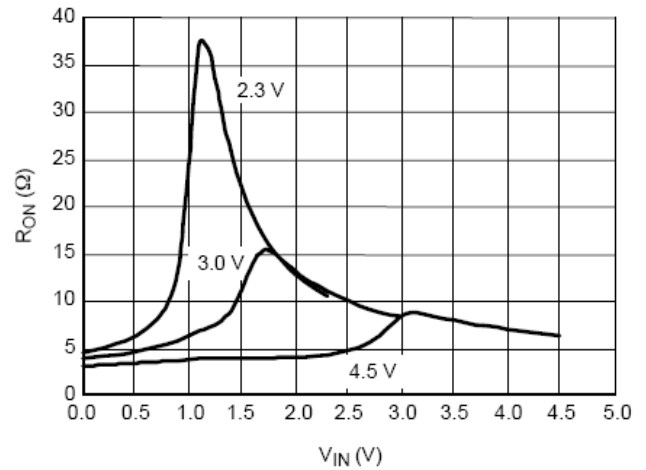
R_{ON} vs. V_{IN} vs. Temperature @ $V_{CC}=3.0V$



R_{ON} vs. V_{IN} vs. Temperature @ $V_{CC}=4.5V$

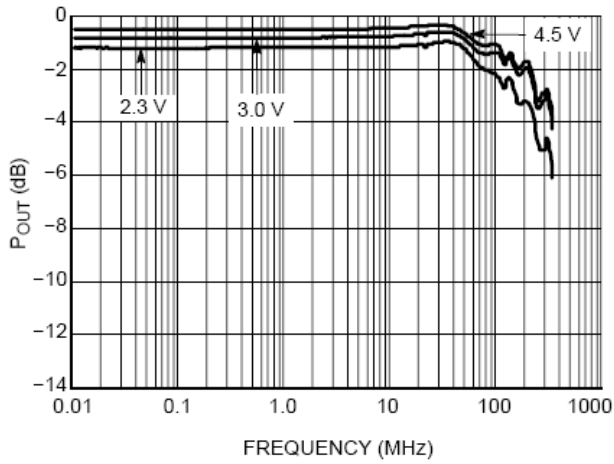


On-Resistance vs. Input Voltage

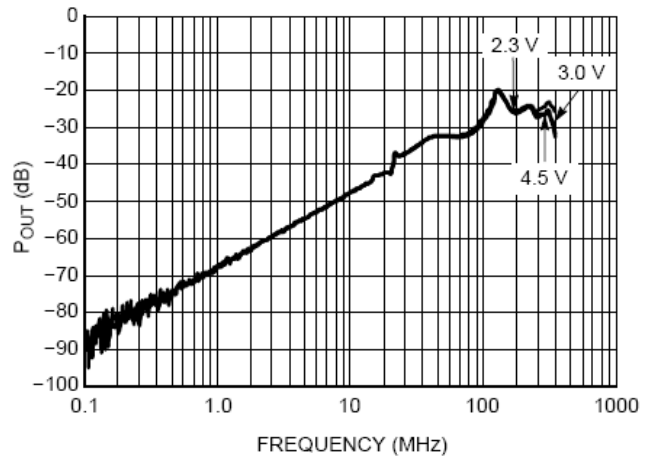


Typical Operating Characteristics (Continued)

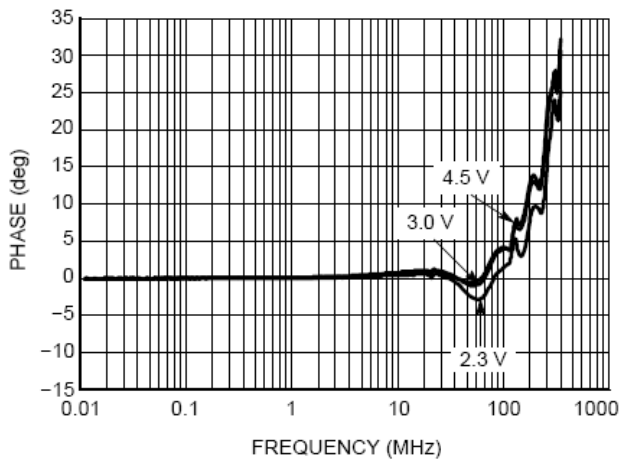
Bandwidth vs. Frequency



Off-Isolation vs. Frequency



Phase Angle vs. Frequency

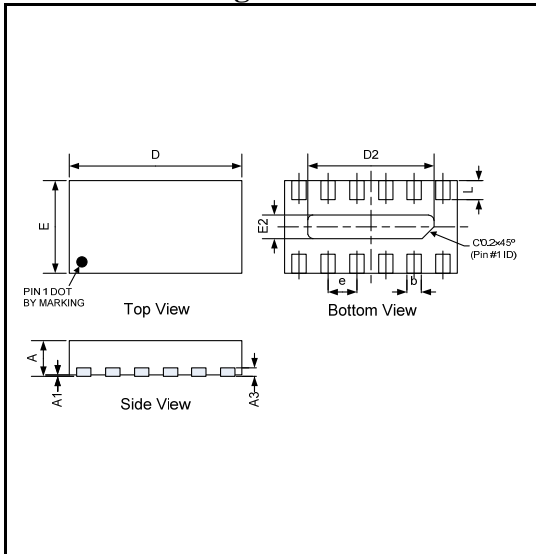


Package Information

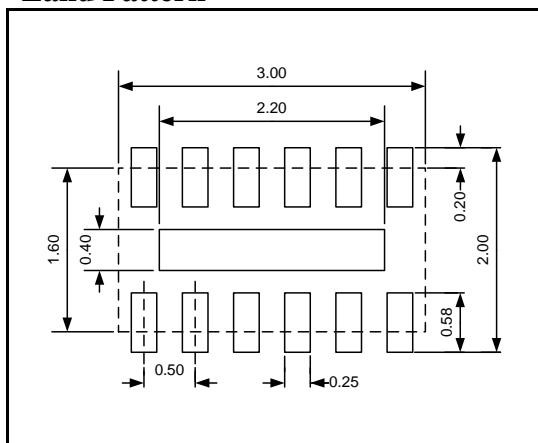
UM3257 DFN12 3.0×1.6

Outline Drawing

DIMENSIONS						
Symbol	MILLIMETERS			INCHES		
	Min	Typ	Max	Min	Typ	Max
A	0.50	0.55	0.605	0.020	0.022	0.024
A1	0.00	-	0.05	0.000	-	0.002
A3	0.15REF			0.006REF		
b	0.20	0.25	0.30	0.008	0.010	0.012
D	2.95	3.00	3.075	0.116	0.118	0.121
D2	2.10	2.20	2.30	0.083	0.087	0.091
E	1.55	1.60	1.675	0.061	0.063	0.066
E2	0.25	-	0.50	0.010	-	0.020
e	0.50TYP			0.020TYP		
L	0.23	-	0.38	0.009	-	0.015



Land Pattern

 <p>The land pattern drawing shows a footprint with a total width of 3.00 mm and a total height of 1.60 mm. The central area has a width of 2.20 mm and a height of 0.40 mm. The distance from the center to the edge is 0.58 mm. The pitch between pins is 0.50 mm, and the distance from the center to the first pin is 0.25 mm.</p>	<p>NOTES:</p> <ol style="list-style-type: none"> 1. Compound dimension: 3.00×1.60; 2. Unit: mm; 3. General tolerance ±0.05mm unless other- wise specified; 4. The layout is just for reference.
--	---

Tape and Reel Orientation



GREEN COMPLIANCE

Union Semiconductor is committed to environmental excellence in all aspects of its operations including meeting or exceeding regulatory requirements with respect to the use of hazardous substances. Numerous successful programs have been implemented to reduce the use of hazardous substances and/or emissions.

All Union components are compliant with the RoHS directive, which helps to support customers in their compliance with environmental directives. For more green compliance information, please visit:

http://www.union-ic.com/index.aspx?cat_code=RoHSDeclaration

IMPORTANT NOTICE

The information in this document has been carefully reviewed and is believed to be accurate. Nonetheless, this document is subject to change without notice. Union assumes no responsibility for any inaccuracies that may be contained in this document, and makes no commitment to update or to keep current the contained information, or to notify a person or organization of any update. Union reserves the right to make changes, at any time, in order to improve reliability, function or design and to attempt to supply the best product possible.



Union Semiconductor, Inc

Add: Unit 606, No.570 Shengxia Road, Shanghai 201210

Tel: 021-51093966

Fax: 021-51026018

Website: www.union-ic.com